UP0187B

Silicon N-channel MOSFET

For switching circuits

■ Features

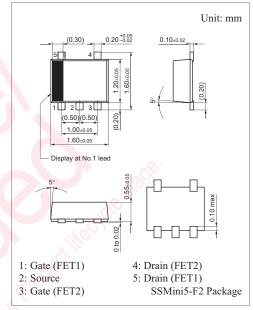
- High-speed switching
- Incorporating a built-in gate protection-diode
- Two elements incorporated into one package
- SSMini type package, reduction of the mounting area and assembly cost

■ Basic Part Number

• 2SK3938 × 2

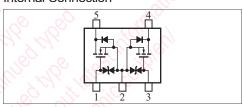
■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|--------------------------------|------------------|-------------|-------|--|
| Drain-source surrender voltage | $V_{ m DSS}$ | 30 | V | |
| Gate-source surrender voltage | V _{GSS} | ±12 | V | |
| Drain current | I_D | 100 | mA | |
| Peak drain current | I_{DP} | 200 | mA | |
| Total power dissipation | P_{T} | 125 | mW | |
| Channel temperature | T _{ch} | 125 | °CO | |
| Storage temperature | T _{stg} | -55 to +125 | °C °C | |



Marking Symbol: 4M

Internal Connection



■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

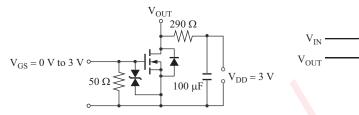
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|---------------------|--|-----|-----|-----|------|
| Drain-source surrender voltage | $V_{\rm DSS}$ | $I_D = 10 \mu A, V_{GS} = 0$ | 30 | | | V |
| Drain-source cutoff current | I _{DSS} | $V_{DS} = 20 \text{ V}, V_{GS} = 0$ | | | 1.0 | μΑ |
| Gate-source cutoff current | I _{GSS} | $V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$ | | | ±10 | μΑ |
| Gate threshold voltage | V _{TH} | $I_D = 1.0 \mu A, V_{DS} = 3.0 V$ | 0.5 | 1.0 | 1.5 | V |
| Drain-source ON resistance | R _{DS(on)} | $I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$ | | 7 | 12 | Ω |
| | | $I_D = 10 \text{ mA}, V_{GS} = 4.0 \text{ V}$ | | 5 | 8 | |
| Forward transfer admittance | Y _{fs} | $I_D = 10 \text{ mA}, V_{DS} = 3 \text{ V}, f = 1 \text{ kHz}$ | 20 | 55 | | mS |
| Short-circuit input capacitance (Common source) | C _{iss} | $V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | | 12 | | pF |
| Short-circuit output capacitance (Common source) | C _{oss} | | | 10 | | pF |
| Reverse transfer capacitance (Common source) | C _{rss} | | | 6 | | pF |
| Turn-on time * | t _{on} | $V_{DD} = 3 \text{ V}, V_{GS} = 0 \text{ V to } 3 \text{ V},$ $I_D = 10 \text{ mA}$ | | 350 | | ns |
| Turn-off time * | t _{off} | $V_{DD} = 3 \text{ V}, V_{GS} = 3 \text{ V to } 0 \text{ V},$ $I_D = 10 \text{ mA}$ | | 350 | | ns |

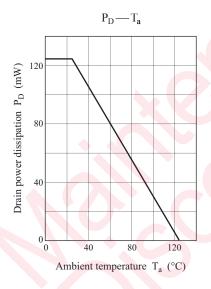
UP0187B Panasonic

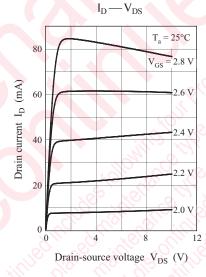
■ Electrical Characteristics (continued) $T_a = 25$ °C±3°C

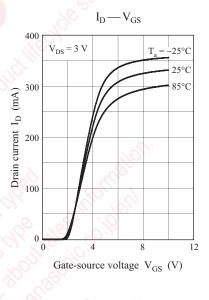
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. * : t_{on} , t_{off} measurement circuit



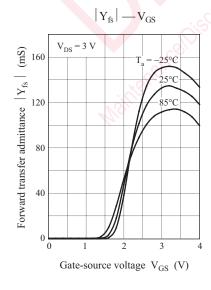


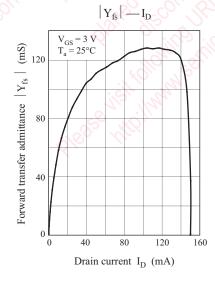


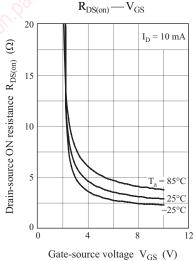


10%

-10%







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